			— Н.
Notice of Allowability	Application No.	Applicant(s)	
	10/750,566	KESHAVARZI ET AL.	
	Examiner	Art Unit	
	Thinh T. Nguyen	2818	
The MAILING DATE of this communication ap All claims being allowable, PROSECUTION ON THE MERITS herewith (or previously mailed), a Notice of Allowance (PTOL-8 NOTICE OF ALLOWABILITY IS NOT A GRANT OF PATENT of the Office or upon petition by the applicant. See 37 CFR 1.3	IS (OR REMAINS) CLOSED in 35) or other appropriate communication is sufficient in the sufficient in th	this application. If not included nication will be mailed in due cours	
1. X This communication is responsive to 10/11/2005.			
2. ⊠ The allowed claim(s) is/are <u>10-15</u> .			
a) ☐ Acknowledgment is made of a claim for foreign priority a) ☐ All b) ☐ Some* c) ☐ None of the: 1. ☐ Certified copies of the priority documents had 2. ☐ Certified copies of the priority documents had 3. ☐ Copies of the certified copies of the priority international Bureau (PCT Rule 17.2(a)). * Certified copies not received: Applicant has THREE MONTHS FROM THE "MAILING DATE noted below. Failure to timely comply will result in ABANDOR THIS THREE-MONTH PERIOD IS NOT EXTENDABLE. 4. ☐ A SUBSTITUTE OATH OR DECLARATION must be sult INFORMAL PATENT APPLICATION (PTO-152) which go so the priority of the priority of the paper No./Mail Date [a) ☐ including changes required by the Notice of Draftsport of the priority of the paper No./Mail Date [b) ☒ including changes required by the attached Examinating Paper No./Mail Date Identifying indicia such as the application number (see 37 CFI each sheet. Replacement sheet(s) should be labeled as such in the decomposition of the decompo	ave been received. ave been received in Application documents have been received E" of this communication to file NMENT of this application. bmitted. Note the attached EXA gives reason(s) why the oath or nust be submitted. erson's Patent Drawing Review— er's Amendment / Comment or R 1.84(c)) should be written on the the header according to 37 CFF posit of BIOLOGICAL MATE	in No in this national stage application from this national stage application from the requirem a reply complying with the requirem MINER'S AMENDMENT or NOTIC declaration is deficient. (PTO-948) attached in the Office action of the drawings in the front (not the back) R 1.121(d). (RIAL must be submitted. Note the	nents E OF
attached Examiner's comment regarding REQUIREMEN	IT FOR THE DEPOSIT OF BIO	LOGICAL MATERIAL.	
Attachment(s) 1. ☐ Notice of References Cited (PTO-892)	5 Nation of lat	ormal Patent Application (PTO-152	١
 Notice of References Cited (P10-892) Divide of Draftperson's Patent Drawing Review (PTO-948) 	8) 6. 🗌 Interview Su	mmary (PTO-413),	,
3. ☐ Information Disclosure Statements (PTO-1449 or PTO/SI		Mail Date Amendment/Comment	
Paper No./Mail Date 4. Examiner's Comment Regarding Requirement for Deposition of Biological Material	it 8. ⊠ Examiner's S	Statement of Reasons for Allowanc	е
	9. 🗆 Other		
	Cavid Nelms		
Super Tec	rvisory Patent Examinar hnology Center 2800		

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DETAILED ACTION

Examiner's Amendment.

1. An examiner's amendment to the record appears below. Should the changes and/or additions be unacceptable to applicant, an amendment may be filed as provided by 37 CFR 1.312. To ensure consideration of such an amendment, it MUST be submitted no later than the payment of the issue fee.

A/ Changes the title to:

-- METHOD FOR MAKING MEMORY CELL WITHOUT HALO IMPLANT—

B/ puts a legend under fig 1 to mark it as "PRIOR ART".

The legend is. necessary in order to clarify what applicant 's invention is (see MPEP paragraph 608.02).

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Reason for allowance

Claims 10-15 are allowed. The following is an examiner's statement of reason for allowance: None of the references of record teaches or suggests the claimed METHOD
 FOR MAKING MEMORY CELL WITHOUT HALO IMPLANT having the limitations:

-- "the memory cell comprising a body region doped with charge carriers of a first type, a source region disposed in the body region and doped with charge carriers of a second type, and a drain region disposed in the body region and doped with charge carriers of the second type, wherein the body region, the source region, and the drain region are oriented in a first direction, wherein the body region and the source region form a first junction, wherein the body region and the drain region form a second junction, and wherein a conductivity of the first junction from the body region to the source region in a case that the first junction is unbiased is substantially less than a conductivity of the second junction from the body region to the drain region in a case that the second junction is unbiased; fabricating a transistor of the device, the transistor oriented in a second direction, wherein the second direction is not parallel to the first direction; and fabricating a halo implant within the transistor, wherein a halo implant is not fabricated in the memory cell. "--

and all other limitations as recited in claim 10.

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Any comments considered necessary by applicant must be submitted no later than the payment of the issue fee and, to avoid processing delays, should preferably accompany the issue fee. Such submissions should be clearly labeled "Comments on Statement of Reasons for Allowance".

Conclusion

3. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Thinh T Nguyen whose telephone number is 571-272-1790. The examiner can normally be reached on Monday-Friday 9:00am-6:00pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, David Nelms can be reached at 571-272-1787. The fax phone numbers for the organization where this application or proceeding is assigned is 571-273-8300.

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Information regarding the status of an application may be obtained from the Patent Application Information Retrieval [PAIR] system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free)

Thinh T Nguyen

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Supervisory Patent Examiner
Technology Center 2800